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74AXP1T57-Q100

Dual supply configurable multiple function gate Rev. 1 — 14 September 2016 Pro

Product data sheet

General description

The 74AXP1T57-Q100 is a dual supply configurable multiple function gate with Schmitt-trigger inputs. It features three inputs (A, B and C), an output (Y) and dual supply pins (V_{CCI} and V_{CCO}). The inputs are referenced to V_{CCI} and the output is referenced to V_{CCO} . All inputs can be connected directly to V_{CCI} or GND. V_{CCI} can be supplied at any voltage between 0.7 V and 2.75 V and V_{CCO} can be supplied at any voltage between 1.2 V and 5.5 V. This feature allows voltage level translation. The 74AXP1T57-Q100 can be configured as any of the following logic functions AND, OR, NAND, NOR, XNOR, inverter and buffer.

This device ensures very low static and dynamic power consumption across the entire supply range and is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

Features and benefits 2.

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range:
 - ◆ V_{CCI}: 0.7 V to 2.75 V
 - V_{CCO}: 1.2 V to 5.5 V
- Low input capacitance; C_I = 0.6 pF (typical)
- Low output capacitance; C_O = 1.8 pF (typical)
- Low dynamic power consumption; C_{PD} = 0.6 pF at V_{CCI} = 1.2 V (typical)
- Low dynamic power consumption; C_{PD} = 7.1 pF at V_{CCO} = 3.3 V (typical)
- Low static power consumption; I_{CCI} = 0.5 μA (85 °C maximum)
- Low static power consumption; I_{CCO} = 1.8 μA (85 °C maximum)
- High noise immunity
- Complies with JEDEC standard:
 - ◆ JESD8-12A.01 (1.1 V to 1.3 V; A, B, C inputs)
 - ◆ JESD8-11A.01 (1.4 V to 1.6 V)
 - ◆ JESD8-7A (1.65 V to 1.95 V)
 - ◆ JESD8-5A.01 (2.3 V to 2.7 V)
 - ◆ JESD8-C (2.7 V to 3.6 V; Y output)
 - JESD12-6 (4.5 V to 5.5 V; Y output)



- ESD protection:
 - ◆ MIL-STD-883, method 3015 Class 2. Exceeds 2 kV
 - ◆ HBM ANSI/ESDA/JEDEC JS-001 Class 2 exceeds 2 kV
 - ◆ CDM JESD22-C101E exceeds 1000 V
- Latch-up performance exceeds 100 mA per JESD78D Class II
- Inputs accept voltages up to 2.75 V
- Low noise overshoot and undershoot < 10% of V_{CCO}
- I_{OFF} circuitry provides partial power-down mode operation

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AXP1T57DC-Q100	–40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1

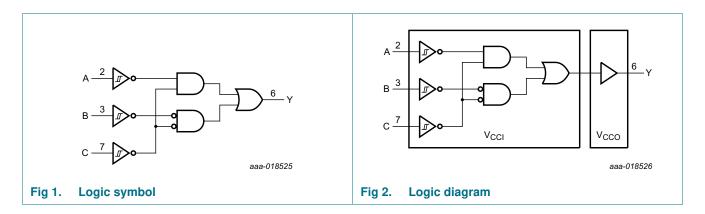
4. Marking

Table 2. Marking

Type number	Marking code[1]
74AXP1T57DC-Q100	rD

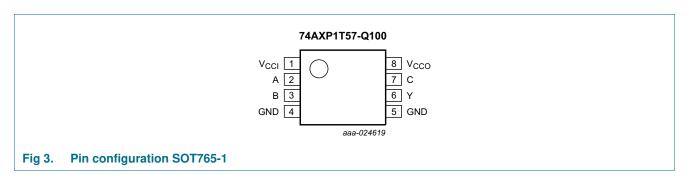
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
V _{CCI}	1	input supply voltage
A, B, C	2, 3, 7	data input
GND[1]	4, 5	ground (0 V)
Υ	6	data output
V _{CCO}	8	output supply voltage

^[1] All GND pins must be connected to ground (0 V).

7. Functional description

Table 4. Function table[1]

Supply voltage	Supply voltage		Input						
V _{CCI}	V _{CCO}	С	В	Α	Υ				
0.7 V to 2.75 V	1.2 V to 5.5 V	L	L	L	Н				
0.7 V to 2.75 V	1.2 V to 5.5 V	L	L	Н	L				
0.7 V to 2.75 V	1.2 V to 5.5 V	L	Н	L	Н				
0.7 V to 2.75 V	1.2 V to 5.5 V	L	Н	Н	L				
0.7 V to 2.75 V	1.2 V to 5.5 V	Н	L	L	L				
0.7 V to 2.75 V	1.2 V to 5.5 V	Н	L	Н	L				
0.7 V to 2.75 V	1.2 V to 5.5 V	Н	Н	L	Н				
0.7 V to 2.75 V	1.2 V to 5.5 V	Н	Н	Н	Н				
GND	1.2 V to 5.5 V	X	X	X	Z				
0.7 V to 2.75 V	GND	X	X	X	Z				
GND	GND	X	Х	X	Z				

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7.1 Logic configurations

Table 5. Function selection table

Logic function	Figure
2-input AND	see Figure 4
2-input AND with both inputs inverted	see Figure 7
2-input NAND with inverted input	see Figure 5 and Figure 6
2-input OR with inverted input	see Figure 5 and Figure 6
2-input NOR	see Figure 7
2-input NOR with both inputs inverted	see Figure 4
2-input XNOR	see Figure 8
Inverter	see Figure 9
Buffer	see Figure 10

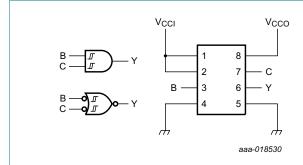


Fig 4. 2-input AND gate or 2-input NOR gate with both inputs inverted

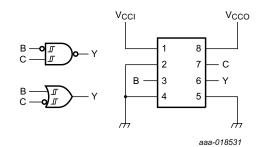


Fig 5. 2-input NAND gate with input B inverted or 2-input OR gate with inverted C input

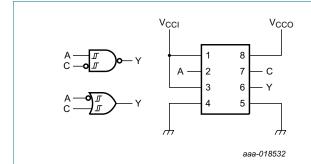


Fig 6. 2-input NAND gate with input C inverted or 2-input OR gate with inverted A input

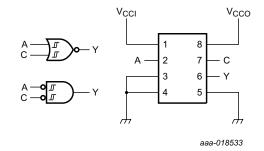
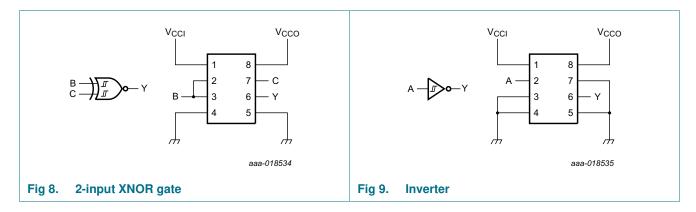
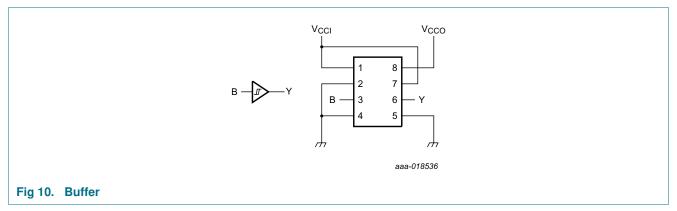


Fig 7. 2-input NOR gate or 2-input AND gate with both inputs inverted





8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CCI}	input supply voltage		-0.5	+3.3	V
V _{CCO}	output supply voltage		-0.5	+6.0	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+3.3	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
V _O	output voltage	Active mode [1][2]	-0.5	$V_{CCO} + 0.5$	V
		Power-down or 3-state mode [1]	-0.5	+6.0	V
I _O	output current	$V_O = 0 \text{ V to } V_{CCO}$	-	±25	mA
I _{CCI}	input supply current		-	50	mA
I _{CCO}	output supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	-	300	mW

- [1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- [2] $V_{CCO} + 0.5 \text{ V}$ should not exceed 6.0 V.
- [3] For VSSOP8 package: above 110 $^{\circ}$ C the value of P_{tot} derates linearly with 8 mW/K.

74AXP1T57_Q100

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9. Recommended operating conditions

Table 7. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CCI}	input supply voltage		0.7	2.75	i V
V _{CCO}	output supply voltage		1.2	5.5	V
VI	input voltage		0	2.75	i V
Vo	output voltage	Active mode	0	V _{CCC}) V
		Power-down or 3-state mode	0	5.5	V
T _{amb}	ambient temperature		-40	+125	oC °C

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions, unless otherwise specified; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		T _{amb}	= -40 °C to	+125 °C		Unit
			Min	Typ 25 °C	Max 25 °C	Max 85 °C	Max 125 °C	
V_{T+}	positive-going threshold	see Figure 11 and Figure 12						
	voltage	V _{CCI} = 0.75 V to 0.85 V	0.3V _{CCI}	-	0.8V _{CCI}	0.8V _{CCI}	0.8V _{CCI}	٧
		V _{CCI} = 1.1 V to 1.95 V	0.4V _{CCI}	-	0.7V _{CCI}	0.7V _{CCI}	0.7V _{CCI}	٧
		V _{CCI} = 2.3 V to 2.7 V	0.9	-	1.7	1.7	1.7	٧
V _{T-}	negative-going threshold	see Figure 11 and Figure 12						
	voltage	V _{CCI} = 0.75 V to 0.85 V	0.2V _{CCI}	-	0.7V _{CCI}	0.7V _{CCI}	0.7V _{CCI}	٧
		V _{CCI} = 1.1 V to 1.95 V	0.3V _{CCI}	-	0.6V _{CCI}	0.6V _{CCI}	0.6V _{CCI}	٧
		V _{CCI} = 2.3 V to 2.7 V	0.7	-	1.5	1.5	1.5	V
	hysteresis voltage	see Figure 11 and Figure 12						
		V _{CCI} = 0.75 V to 0.85 V	0.06V _{CCI}	-	0.5V _{CCI}	0.5V _{CCI}	0.5V _{CCI}	V
		V _{CCI} = 1.1 V to 1.95 V	0.1V _{CCI}	-	0.4V _{CCI}	0.4V _{CCI}	0.4V _{CCI}	٧
		V _{CCI} = 2.3 V to 2.7 V	0.2	-	1.0	1.0	1.0	٧
V _{OH}	HIGH-level output voltage	$I_{O} = -2 \text{ mA};$ [1] $V_{CCO} = 1.2 \text{ V}$	-	1.05	-	-	-	V
		$I_{O} = -3 \text{ mA};$ $V_{CCO} = 1.4 \text{ V}$	1.05	-	-	-	-	V
		$I_{O} = -4.5 \text{ mA};$ $V_{CCO} = 1.65 \text{ V}$	1.2	-	-	-	-	V
		$I_O = -8 \text{ mA};$ $V_{CCO} = 2.3 \text{ V}$	1.7	-	-	-	-	V
		$I_O = -10 \text{ mA};$ $V_{CCO} = 3.0 \text{ V}$	2.2	-	-	-	-	V
		$I_O = -12 \text{ mA};$ $V_{CCO} = 4.5 \text{ V}$	3.7	-	-	-	-	V

 Table 8.
 Static characteristics ... continued

At recommended operating conditions, unless otherwise specified; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions			T _{amb}	= -40 °C to	+125 °C		Unit
				Min	Typ 25 °C	Max 25 °C	Max 85 °C	Max 125 °C	
V_{OL}	LOW-level	$I_O = 2 \text{ mA}; V_{CCO} = 1.2 \text{ V}$	<u>[1]</u>	-	0.18	-	-	-	V
	output voltage	$I_O = 3 \text{ mA}; V_{CCO} = 1.4 \text{ V}$		-	-	0.35	0.35	0.35	V
		I _O = 4.5 mA; V _{CCO} = 1.65 V		-	-	0.45	0.45	0.45	٧
		$I_O = 8 \text{ mA}; V_{CCO} = 2.3 \text{ V}$		-	-	0.7	0.7	0.7	٧
		I _O = 10 mA; V _{CCO} = 3.0 V		-	-	0.8	0.8	0.8	V
		I _O = 12 mA; V _{CCO} = 4.5 V		-	-	0.8	0.8	0.8	V
II	input leakage current	V _I = 0 V to 2.75 V; V _{CCI} = 0 V to 2.75 V	<u>[1]</u>	-	±0.001	±0.1	±0.5	±1.0	μА
I _{OZ}	OFF-state output current	$V_O = 0 \text{ V to } 5.5 \text{ V};$ $V_{CCO} = 1.2 \text{ V to } 5.5 \text{ V}$		-	±0.001	±0.1	±0.5	±2.0	μА
l _{OFF}	power-off leakage current	$\begin{aligned} &\text{inputs; } V_I = 0 \text{ V to } 2.75 \text{ V;} \\ &V_{CCI} = 0 \text{ V;} \\ &V_{CCO} = 0 \text{ V to } 5.5 \text{ V} \end{aligned}$	[1]	-	±0.01	±0.1	±0.5	±2.0	μА
		output; $V_O = 0 \text{ V to } 5.5 \text{ V};$ $V_{CCO} = 0 \text{ V};$ $V_{CCI} = 0 \text{ V to } 2.75 \text{ V};$ $V_I = 0 \text{ V to } 2.75 \text{ V}$	[1]	-	±0.01	±0.1	±0.5	±2.0	μА
ΔI_{OFF}	additional power-off leakage		[1]	-	±0.02	±0.1	±0.5	±2.0	μА
	current		<u>[1]</u>	-	±0.02	±0.1	±0.5	±2.0	μА

[1] Typical values are measured at $V_{CCI} = V_{CCO} = 1.2 \text{ V}$ unless otherwise specified.

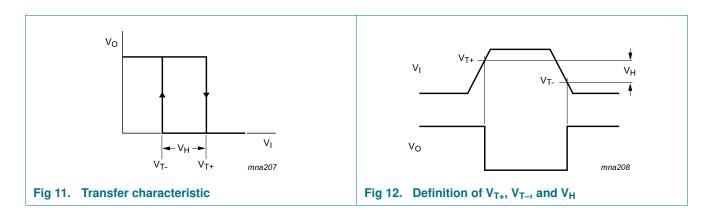


Table 9. Static characteristics supply current

At recommended operating conditions, unless otherwise specified; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		T _{amb} =	-40 °C to	+125 °C		Unit
			Typ 25 °C	Max 25 °C	Typ 85 °C	Max 85 °C	Max 125 °C	
I _{CCI}	input supply	$V_I = 0 \text{ V or } V_{CCI};$						
	current	V _{CCI} = 0.7 V to 1.3 V [1]	1	100	10	300	500	nA
		V _{CCI} = 1.3 V to 2.75 V [2]	1	100	20	500	1000	nA
		V _{CCI} = 2.75 V; V _{CCO} = 0 V	1	100	20	500	1000	nA
		V _{CCI} = 0 V; V _{CCO} = 5.5 V	1	100	1	100	500	nA
I _{CCO}	$ \begin{array}{ll} \text{output supply} & V_l = 0 \text{ V or } V_{CCl}; \\ \text{current} & I_O = 0 \text{ A; see } \underline{\text{Table 10}} \\ \end{array} $							
		$V_{CCO} = 1.2 \text{ V to } 3.6 \text{ V}$	0.001	1.0	0.01	1.2	1.3	μΑ
		$V_{CCO} = 3.6 \text{ V to } 5.5 \text{ V}$	0.8	1.5	1.0	1.8	2.0	μΑ
		V _{CCI} = 2.75 V; V _{CCO} = 0 V	0.001	0.1	0.003	0.2	0.5	μΑ
		V _{CCI} = 0 V; V _{CCO} = 3.6 V	0.2	0.6	0.3	0.8	1.2	μΑ
		V _{CCI} = 0 V; V _{CCO} = 5.5 V	0.4	0.8	0.5	1.0	1.5	μΑ
Δl _{CCI}	additional input supply current	$\begin{aligned} V_I &= V_{CCI} - 0.5 \ V; \\ V_{CCI} &= 2.5 \ V \end{aligned}$	2	100	14	150	200	μΑ

^[1] Typical values are measured at $V_{CCI} = V_{CCO} = 1.2 \text{ V}$.

Table 10. Typical output supply current (I_{CCO})

V _{CCI}	V _{cco}	V _{CCO}												
	0 V 1.2 V 1.5 V		1.5 V	1.8 V 2.5 V		3.3 V	5.0 V							
0 V	0	1	5	20	100	200	400	nA						
0.8 V	1	10	150	200	300	500	800	nA						
1.2 V	1	1	5	200	300	500	800	nA						
1.5 V	1	1	5	100	300	500	800	nA						
1.8 V	1	1	5	100	300	500	800	nA						
2.5 V	1	1	5	100	100	500	800	nA						

^[2] Typical values are measured at $V_{CCI} = V_{CCO} = 2.5 \text{ V}$.

^[3] Typical values are measured at $V_{CCI} = 1.2 \text{ V}$ and $V_{CCO} = 5.0 \text{ V}$.

11. Dynamic characteristics

Table 11. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see <u>Figure 20</u>; for wave form, see <u>Figure 13</u>.

Symbol	Parameter	Conditions								Vccc	<u>[1]</u>								Unit
			1.2 V	1.5	V ± 0.	1 V	1.8	V ± 0.1	15 V	2.5	V ± 0.	2 V	3.3	V ± 0.	3 V	5.0	V ± 0.	5 V	
			Тур	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
T _{amb} = 2	5 °C																		
t _{pd}		A, B and C to Y																	
	delay	V _{CCI} = 0.75 V to 0.85 V	25	4	20	76	4	18	72	3	16	72	3	16	80	3	17	92	ns
		V _{CCI} = 1.1 V to 1.3 V	16.5	3.4	10.9	21.0	3.0	8.9	17.0	2.6	7.3	12.0	2.5	6.7	10.7	2.4	6.4	10.2	ns
		V _{CCI} = 1.4 V to 1.6 V	15.5	3.1	9.9	19.0	2.6	7.9	14.0	2.3	6.2	9.9	2.1	5.6	9.0	2.1	5.3	8.5	ns
		V _{CCI} = 1.65 V to 1.95 V	15.0	2.6	9.4	18.0	2.1	7.4	12.5	1.7	5.7	9.3	1.6	5.1	8.3	1.5	4.8	7.9	ns
		$V_{CCI} = 2.3 \text{ V to } 2.7 \text{ V}$	14.5	2.7	8.9	17.5	2.2	6.9	11.7	1.9	5.2	8.7	1.8	4.6	7.7	1.7	4.3	7.2	ns
T _{amb} = -	40 °C to +85 °	°C																	
		A, B and C to Y																	
	delay	V _{CCI} = 0.75 V to 0.85 V	25	3	20	151	3	18	148	2	16	167	2	16	194	2	17	225	ns
		V _{CCI} = 1.1 V to 1.3 V	16.5	3.4	10.9	21.0	3.0	8.9	17.0	2.6	7.3	12.0	2.5	6.7	10.7	2.4	6.4	10.2	ns
		V _{CCI} = 1.4 V to 1.6 V	15.5	3.1	9.9	19.0	2.6	7.9	14.0	2.3	6.2	9.9	2.1	5.6	9.0	2.1	5.3	8.5	ns
		V _{CCI} = 1.65 V to 1.95 V	15.0	2.6	9.4	18.0	2.1	7.4	12.5	1.7	5.7	9.3	1.6	5.1	8.3	1.5	4.8	7.9	ns
		$V_{CCI} = 2.3 \text{ V to } 2.7 \text{ V}$	14.5	2.7	8.9	17.5	2.2	6.9	11.7	1.9	5.2	8.7	1.8	4.6	7.7	1.7	4.3	7.2	ns
T _{amb} = -	40 °C to +125	S °C																	
t _{pd}		A, B and C to Y																	
	delay	V _{CCI} = 0.75 V to 0.85 V	25	3	20	151	3	18	148	2	16	167	2	16	194	2	17	225	ns
		V _{CCI} = 1.1 V to 1.3 V	16.5	3.4	10.9	21.0	3.0	8.9	17.5	2.6	7.3	15.0	2.5	6.7	13.0	2.4	6.4	12.0	ns
		V _{CCI} = 1.4 V to 1.6 V	15.5	3.1	9.9	20.0	2.6	7.9	16.5	2.3	6.2	12.0	2.1	5.6	10.9	2.1	5.3	10.3	ns
		V _{CCI} = 1.65 V to 1.95 V	15.0	2.6	9.4	19.0	2.1	7.4	15.5	1.7	5.7	11.3	1.6	5.1	10.4	1.5	4.8	9.7	ns
		V _{CCI} = 2.3 V to 2.7 V	14.5	2.7	8.9	18.0	2.2	6.9	14.5	1.9	5.2	10.6	1.8	4.6	9.6	1.7	4.3	8.9	ns
t _t	transition time	V _{CCI} = 0.75 V to 2.7 V	-	1.0	-	-	1.0	-	-	1.0	-	-	1.0	-	-	1.0	-	-	ns

^[1] Typical values are measured at nominal supply voltages and T_{amb} = +25 °C.

^{2]} t_{pd} is the same as t_{PLH} and t_{PHL} .

^[3] t_t is the same as t_{THL} and t_{TLH} .

Table 12. Typical dynamic characteristics at T_{amb} = 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 20; for wave form, see Figure 13.

Symbol	Parameter	Conditions		V _{CCO}				Unit	
				1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; R_L = \infty \Omega; V_I = 0 \text{ V to } V_{CCI}$ [1]							
		input supply [2]							
		V _{CCI} = 0.8 V	0.5	0.5	0.5	0.5	0.5	0.5	pF
		V _{CCI} = 1.2 V	0.6	0.6	0.6	0.6	0.6	0.6	pF
		V _{CCI} = 1.5 V	0.7	0.7	0.7	0.7	0.7	0.7	pF
		V _{CCI} = 1.8 V	0.8	0.8	0.8	0.8	0.8	0.8	pF
		V _{CCI} = 2.5 V	1.0	1.0	1.0	1.0	1.0	1.0	pF
		output supply [3]							
		V _{CCI} = 0.8 V	6.7	6.8	6.8	6.9	7.5	9.5	pF
		V _{CCI} = 1.2 V	6.8	6.9	7.0	7.0	7.1	7.6	pF
		V _{CCI} = 1.5 V	6.9	6.9	6.9	7.0	7.1	7.6	pF
		V _{CCI} = 1.8 V	6.9	6.9	6.9	7.0	7.2	7.6	pF
		V _{CCI} = 2.5 V	6.9	7.0	7.0	7.0	7.2	7.6	pF
Cı	input capacitance	$V_I = 0 \text{ V or } V_{CCI}; V_{CCI} = 0 \text{ V to } 2.7 \text{ V}$	0.6	0.6	0.6	0.6	0.6	0.6	pF
Co	output capacitance	$V_O = 0 \text{ V}; V_{CCO} = 0 \text{ V}$	1.8	1.8	1.8	1.8	1.8	1.8	pF

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

[2] Power dissipated from input supply (V_{CCI})

 $P_D = C_{PD} \times V_{CCI}{}^2 \times f_i \times N$ where:

 C_{PD} = power dissipation capacitance of the input supply.

V_{CCI} = input supply voltage in V;

f_i = input frequency in MHz;

N = number of inputs switching;

[3] Power dissipated from output supply (V_{CCO})

 $P_D = (C_L + C_{PD}) \times V_{CCO}^2 \times f_o$ where:

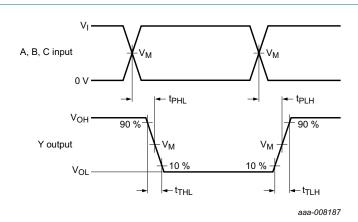
C_L = load capacitance in pF;

 C_{PD} = power dissipation capacitance of the output supply.

 V_{CCO} = output supply voltage in V;

 $f_o = output frequency in MHz;$

11.1 Waveforms and graphs



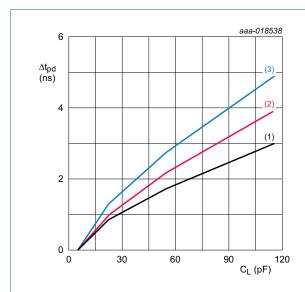
Measurement points are given in <u>Table 13</u>.

 $\ensuremath{V_{\text{OL}}}$ and $\ensuremath{V_{\text{OH}}}$ are typical output voltage drops that occur with the output load.

Fig 13. Input A, B and C to output Y propagation delay times and output transition times

Table 13. Measurement points

Supply voltage		Output	Input		
V _{CCI}	V _{CCO}	V _M	V _M	VI	
0.75 V to 2.7 V	1.2 V to 5.5 V	0.5V _{CCO}	0.5V _{CCI}	V _{CCI}	



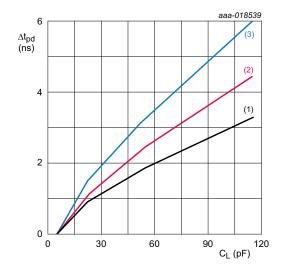
 $T_{amb} = -40$ °C to +85 °C unless otherwise specified.

(1) Minimum: $V_{CCO} = 5.5 \text{ V}$

(2) Typical: $T_{amb} = 25 \, ^{\circ}C$; $V_{CCO} = 5 \, V$

(3) Maximum: V_{CCO} = 4.5 V

Fig 14. Additional propagation delay versus load capacitance



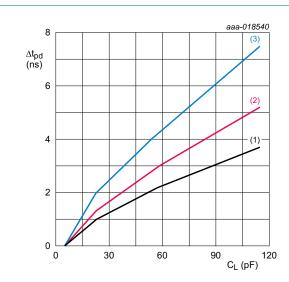
 $T_{amb} = -40 \, ^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$ unless otherwise specified.

(1) Minimum: $V_{CCO} = 3.6 \text{ V}$

(2) Typical: $T_{amb} = 25 \, ^{\circ}C$; $V_{CCO} = 3.3 \, V$

(3) Maximum: V_{CCO} = 3 V

Fig 15. Additional propagation delay versus load capacitance



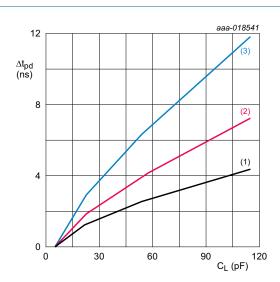
 T_{amb} = -40 °C to +85 °C unless otherwise specified.

(1) Minimum: $V_{CCO} = 2.7 \text{ V}$

(2) Typical: $T_{amb} = 25 \,^{\circ}C$; $V_{CCO} = 2.5 \,^{\circ}V$

(3) Maximum: V_{CCO} = 2.3 V

Fig 16. Additional propagation delay versus load capacitance



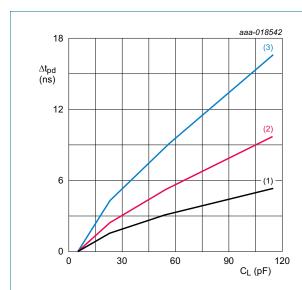
 $T_{amb} = -40$ °C to +85 °C unless otherwise specified.

(1) Minimum: $V_{CCO} = 1.95 \text{ V}$

(2) Typical: $T_{amb} = 25 \, ^{\circ}C$; $V_{CCO} = 1.8 \, V$

(3) Maximum: V_{CCO} = 1.65 V

Fig 17. Additional propagation delay versus load capacitance



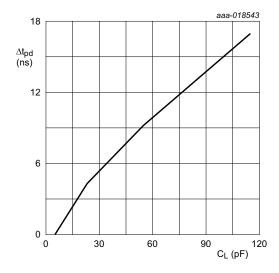
 $T_{amb} = -40 \, ^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$ unless otherwise specified.

(1) Minimum: $V_{CCO} = 1.6 \text{ V}$

(2) Typical: $T_{amb} = 25 \, ^{\circ}C$; $V_{CCO} = 1.5 \, V$

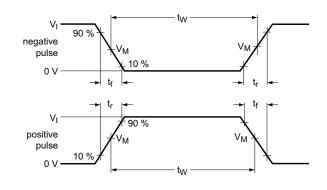
(3) Maximum: V_{CCO} = 1.4 V

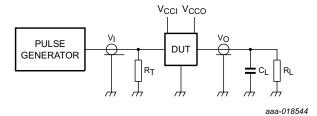
Fig 18. Additional propagation delay versus load capacitance



 T_{amb} = 25 °C; V_{CCO} = 1.2 V.

Fig 19. Additional propagation delay versus load capacitance





Test data is given in Table 14.

Definitions test circuit:

 R_T = termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = load capacitance including jig and probe capacitance.

 R_L = Load resistance.

Fig 20. Test circuit for measuring switching times

Table 14. Test data

Supply voltage		Load		Input	
V _{CCI}	V _{CCO}	CL	RL	t _r , t _f	VI
0.75 V to 2.7 V	1.2 V to 5.5 V	5 pF	5 kΩ	≤3.0 ns	V _{CCI}

12. Package outline

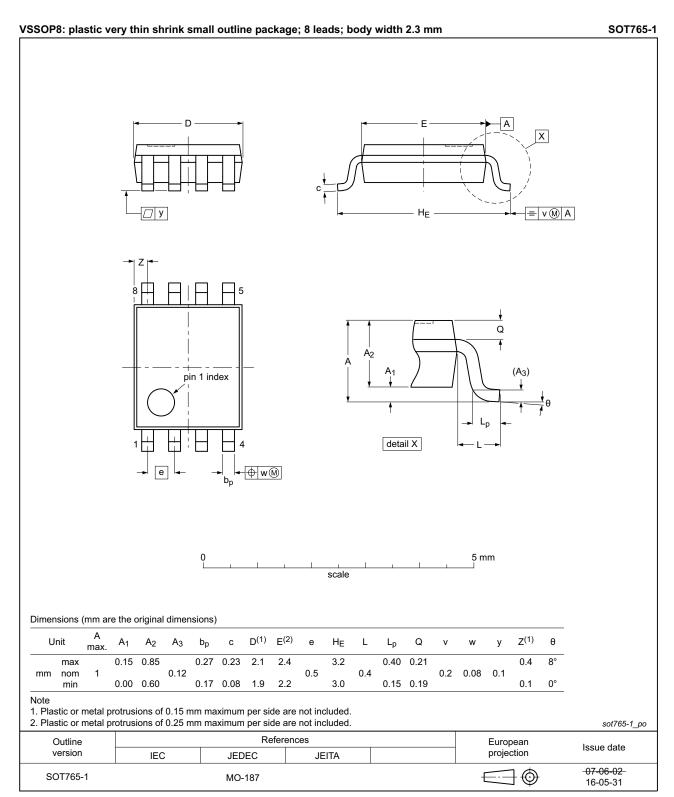


Fig 21. Package outline SOT765-1 (VSSOP8)

13. Abbreviations

Table 15. Abbreviations

Acronym	Description
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
MIL	Military

14. Revision history

Table 16. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AXP1T57_Q100 v.1	20160914	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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